Three quadrant triacs guaranteed commutation

## GENERAL DESCRIPTION

Passivated guaranteed commutation triacs in a full pack, plastic envelope intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

## QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MAX. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \mathrm{V}_{\mathrm{DRM}} \\ & \mathrm{I}_{\mathrm{T}(\mathrm{RMS})} \\ & \mathrm{I}_{\mathrm{TSM}} \end{aligned}$ | BTA208X- BTA208X- | 600D 600E | 800E |  |
|  | BTA208X- | 600F | 800F |  |
|  | Repetitive peak off-state voltages <br> RMS on-state current Non-repetitive peak on-state current | 600 | 800 | V |
|  |  |  |  |  |
|  |  | 8 | 8 | A |
|  |  | 65 | 65 | A |

PINNING - SOT186A

| PIN | DESCRIPTION |
| :---: | :--- |
| 1 | main terminal 1 |
| 2 | main terminal 2 |
| 3 | gate |
| case | isolated |

PIN CONFIGURATION


SYMBOL


## LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).


[^0]ISOLATION LIMITING VALUE \& CHARACTERISTIC
$\mathrm{T}_{\text {hs }}=25^{\circ} \mathrm{C}$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| V $_{\text {isol }}$ | R.M.S. isolation voltage from all <br> three terminals to external <br> heatsink | $\mathrm{f}=50-60 \mathrm{~Hz}$; sinusoidal <br> waveform; <br> R.H. $\leq 65 \% ;$ clean and dustfree | - | - | 2500 | V |
| C $_{\text {isol }}$ | Capacitance from T2 to external <br> heatsink | $\mathrm{f}=1 \mathrm{MHz}$ | - | 10 | - | pF |

## THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| :--- | :--- | :--- | :---: | :---: | :---: | :---: |
| $R_{\text {th } j \text {-hs }}$ | Thermal resistance <br> junction to heatsink | full or half cycle <br> with heatsink compound <br> without heatsink compound <br> $R_{\text {th } j-a}$ | Thermal resistance <br> junction to ambient | in free air | - | - |

## STATIC CHARACTERISTICS

$\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{GT}}$ | Gate trigger current ${ }^{2}$ | BTA208X- |  | ...D | ...E | ...F |  |
|  |  | $\mathrm{V}_{\mathrm{D}}=12 \mathrm{~V} ; \mathrm{I}_{T}=0.1 \mathrm{~A}$ |  |  |  |  |  |
|  |  | T2+ G+ | - | 5 | 10 | 25 | mA |
|  |  | T2+ G- | - | 5 | 10 | 25 | mA |
|  |  | T2- G- | - | 5 | 10 | 25 | mA |
| $\mathrm{I}_{\mathrm{L}}$ | Latching current | $\begin{aligned} & \mathrm{V}_{\mathrm{D}}=12 \mathrm{~V} ; \mathrm{I}_{\mathrm{GT}}=0.1 \mathrm{~A} \\ & \mathrm{~T} 2+\mathrm{G}+ \\ & \mathrm{T} 2+\mathrm{G}- \\ & \mathrm{T} 2-\mathrm{G}- \end{aligned}$ |  |  |  |  |  |
|  |  |  | - | 15 | 25 | 30 | mA |
|  |  |  | - | 25 | 30 | 40 | mA |
|  |  |  | - | 25 | 30 | 40 | mA |
| $\mathrm{I}_{\mathrm{H}}$ | Holding current | $\mathrm{V}_{\mathrm{D}}=12 \mathrm{~V} ; \mathrm{I}_{\mathrm{GT}}=0.1 \mathrm{~A}$ | - | 15 | 25 | 30 | mA |
| $\begin{aligned} & V_{T} \\ & V_{G T} \end{aligned}$ | On-state voltage Gate trigger voltage | $\begin{aligned} & \mathrm{I}_{T}=10 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{D}}=12 \mathrm{~V} ; \mathrm{I}_{T}=0.1 \mathrm{~A} \\ & \mathrm{~V}_{\mathrm{D}}=400 \mathrm{~V} ; \mathrm{I}_{T}=0.1 \mathrm{~A} ; \end{aligned}$ | - | 1.65 |  |  | V |
|  |  |  | - |  | 1.5 |  | V |
|  |  |  | 0.25 |  | - |  | V |
|  |  | $\mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ |  |  |  |  |  |
| $\mathrm{I}_{\mathrm{D}}$ | Off-state leakage current | $\mathrm{V}_{\mathrm{D}}=\mathrm{V}_{\text {DRM }(\text { max })} ; \mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$ | - |  | 0.5 |  | mA |

[^1]Three quadrant triacs
BTA208X series D, E and F guaranteed commutation

## DYNAMIC CHARACTERISTICS

$\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. |  |  | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | BTA208X- | ...D | ...E | ...F |  |  |
| $\mathrm{dV} / \mathrm{dt}$ | Critical rate of rise of off-state voltage | $\mathrm{V}_{\mathrm{DM}}=67 \% \mathrm{~V}_{\text {DRM(max) }}$; $\mathrm{T}_{\mathrm{j}}=110^{\circ} \mathrm{C}$; exponential waveform; gate open | 20 | 60 | 70 | - | V/us |
| $\mathrm{dl}_{\text {com }} / \mathrm{dt}$ | Critical rate of change of commutating current | circuit <br> $\mathrm{V}_{\mathrm{DM}}=400 \mathrm{~V} ; \mathrm{T}_{\mathrm{j}}=125^{\circ} \mathrm{C}$; <br> $\mathrm{I}_{\text {T(RMS) }}=8 \mathrm{~A}$; <br> $\mathrm{d} \mathrm{V}_{\text {com }} / \mathrm{dt}=10 \mathrm{~V} / \mathrm{\mu s}$; gate | 2 | 5 | 14 | - | A/ms |
| $\mathrm{dl}_{\text {com }} / \mathrm{dt}$ | Critical rate of change of commutating current |  | 6 | 10 | 20 | - | A/ms |

## Three quadrant triacs guaranteed commutation



Fig.1. Maximum on-state dissipation, $P_{\text {tot }}$, versus rms on-state current, $I_{T(R M S)}$, where $\alpha=$ conduction angle.


Fig.2. Maximum permissible non-repetitive peak on-state current $I_{\text {TSM }}$, versus pulse width $t_{p}$, for sinusoidal currents, $t_{p} \leq 20 \mathrm{~ms}$.


Fig.3. Maximum permissible non-repetitive peak on-state current $I_{T S M}$, versus number of cycles, for sinusoidal currents, $f=50 \mathrm{~Hz}$.


Fig.4. Maximum permissible rms current $I_{T(R M S)}$, versus heatsink temperature $T_{h s}$.


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(B M S)}$, versus surge duration, for sinusoidal currents, $f=50 \mathrm{~Hz} ; T_{h s} \leq 73^{\circ} \mathrm{C}$.


Fig.6. Normalised gate trigger voltage $V_{G T}\left(T_{j}\right) / V_{G T}\left(25^{\circ} \mathrm{C}\right)$, versus junction temperature $T_{j}$.

Three quadrant triacs
BTA208X series D, E and F guaranteed commutation


Fig.7. Normalised gate trigger current $I_{G T}\left(T_{j}\right) / I_{G T}\left(25^{\circ} \mathrm{C}\right)$, versus junction temperature $T_{j}$.


Fig.8. Normalised latching current $I_{L}\left(T_{j}\right) / I_{L}\left(25^{\circ} \mathrm{C}\right)$, versus junction temperature $T_{j}$.


Fig.9. Normalised holding current $I_{H}\left(T_{j}\right) / I_{H}\left(25^{\circ} \mathrm{C}\right)$, versus junction temperature $T_{j}$.


Fig.10. Typical and maximum on-state characteristic.


Fig.11. Transient thermal impedance $Z_{\text {th } j-\text {-ns }}$, versus pulse width $t_{p}$.


Fig.12. Miniumum, critical rate of change of commutating current $d l_{\text {com }} / d t$ versus junction temperature, $d V_{\text {com }}^{\text {com }} / d t=20 \mathrm{~V} / \mu \mathrm{s}$

Three quadrant triacs
BTA208X series D, E and F guaranteed commutation

## MECHANICAL DATA



Fig.13. SOT186A; The seating plane is electrically isolated from all terminals.

## Notes

1. Refer to mounting instructions for F-pack envelopes.
2. Epoxy meets UL94 V0 at $1 / 8$ ".

Three quadrant triacs
BTA208X series D, E and F guaranteed commutation

## DEFINITIONS

| DATA SHEET STATUS |  |  |
| :---: | :---: | :---: |
| DATA SHEET STATUS ${ }^{3}$ | PRODUCT STATUS ${ }^{4}$ | DEFINITIONS |
| Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice |
| Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product |
| Product data | Production | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A |
| Limiting values |  |  |
| Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |  |  |
| Application information |  |  |
| Where application information is given, it is advisory and does not form part of the specification. |  |  |
| © Philips Electronics N.V. 2002 |  |  |
| All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. |  |  |
| The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights. |  |  |

## LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

[^2]4 The product status of the device(s) described in this datasheet may have changed since this datasheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.


[^0]:    1 Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed $6 \mathrm{~A} / \mu \mathrm{s}$.

[^1]:    2 Device does not trigger in the T2-, G+ quadrant.

[^2]:    3 Please consult the most recently issued datasheet before initiating or completing a design.

